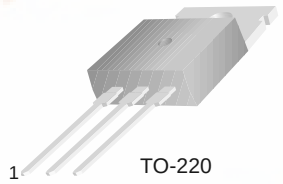
FAIRCHILD SEMICONDUCTOR™

KSC2233

B/W TV Horizontal Deflection Output

- Collector-Base Voltage : V_{CBO} = 200V
- Collector Current (DC) : I_C = 4A
- Collector Dissipation : P_C = 40W



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1.Base 2.Collector 3.Emitter

NPN Epitaxial Silicon Transistor

Absolute Maximum Ratings T_C=25°C unless otherwise noted

Symbol	Parameter	Value	Units
V_{CBO}	Collector-Base Voltage	200	V
V_{CEO}	Collector-Emitter Voltage	60	V
V_{EBO}	Emitter-Base Voltage	5	V
I_C	Collector Current	4	A
P_C	Collector Dissipation (T_C=25°C)	40	W
T_J	Junction Temperature	150	°C
T_{STG}	Storage Temperature	-55 ~ +150	°C

Electrical Characteristics T_C=25°C unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Typ.	Max.	Units
BV_{CBO}	Collector-Base Breakdown Voltage	I_C = 1mA, I_E = 0	200			V
BV_{CEO}	Collector-Emitter Breakdown Voltage	I_C = 20mA, I_B =0	60			V
BV_{EBO}	Emitter-Base Breakdown Voltage	I_E = 1mA, I_C = 0	5			V
I_{CBO}	Collector Cut-off Current	V_{CB} = 170V, I_E = 0			10	μA
h_{FE1} h_{FE2}	DC Current Gain	V_{CE} = 5V, I_C = 1A V_{CE} = 5V, I_C = 4A	30 20	 40	150	
V_{CE}(sat)	Collector-Emitter Saturation Voltage	I_C = 4A, I_B = 0.4A			1	V
V_{BE}(sat)	Base-Emitter Saturation Voltage	I_C = 4A, I_B = 0.4A			1.5	V
f_T	Current Gain Bandwidth Product	V_{CE} = 5V, I_C = 0.5A		10		MHz

Typical Characteristics

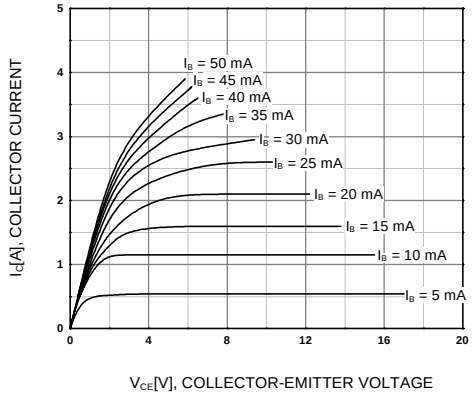

Figure 1. Static Characteristic

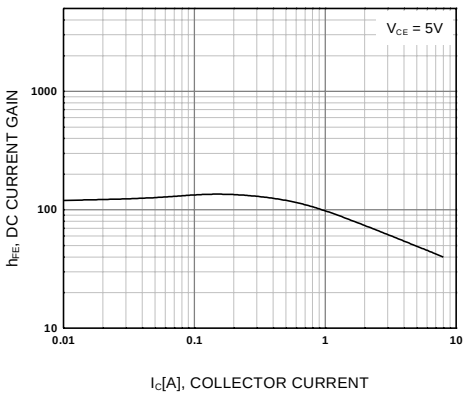

Figure 2. DC current Gain

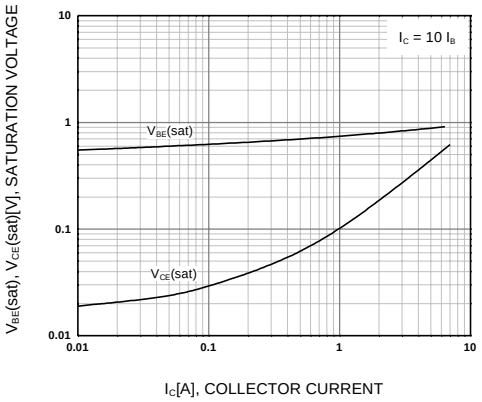

Figure 3. Base-Emitter Saturation Voltage Collector-Emitter Saturation Voltage

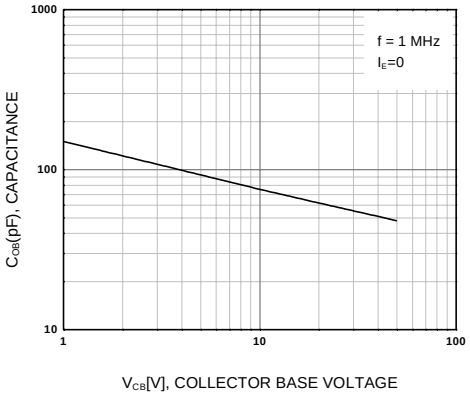

Figure 4. Collector Output Capacitance

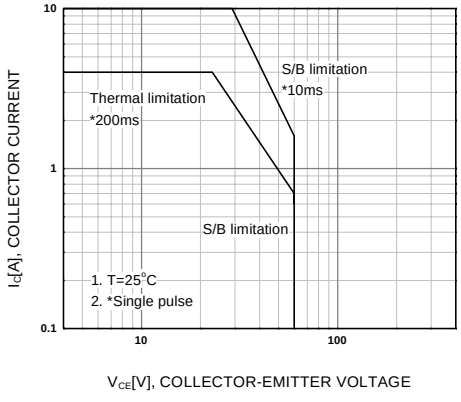

Figure 5. Safe Operating Area

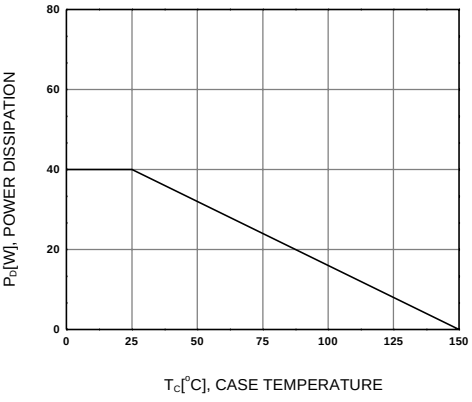

Figure 6. Power Derating

Package Demensions

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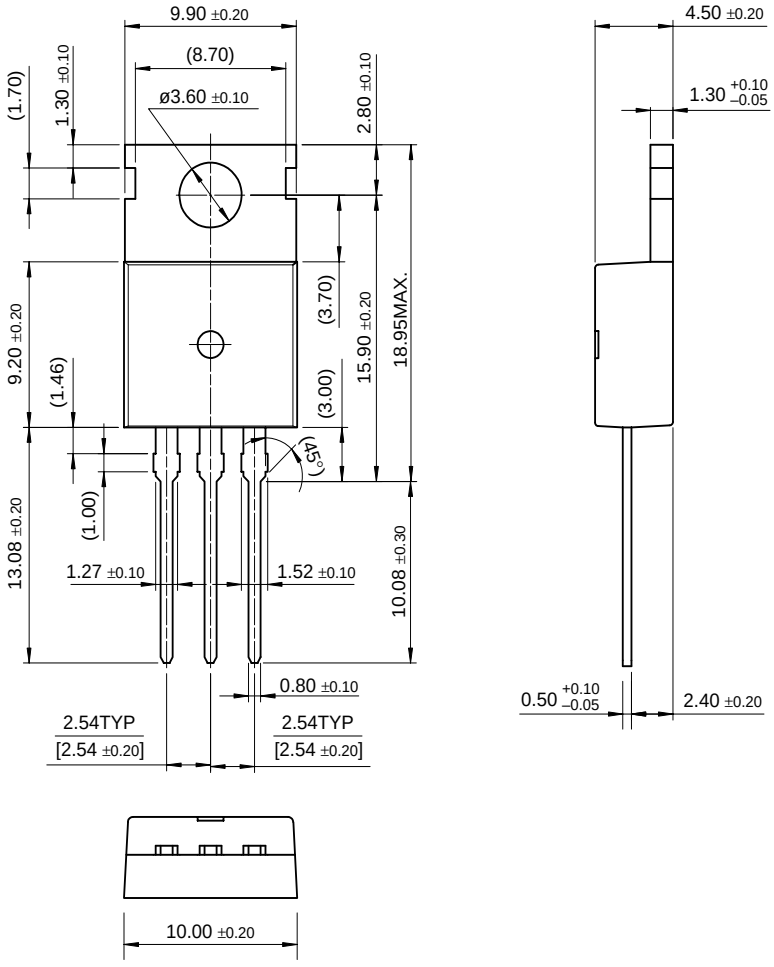

Dimensions in Millimeters

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